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Docket No.: M4065.0743/P743
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Steven T. Harshfield, et al

Application No.: 09/853,233

Group Art Unit: 2823

Filed: May 11, 2001

Examiner: Coleman, V

For: PCRAM MEMORY CELL AND METHOD
OF MAKING SAME

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TECHNOLOGY CENTER 2800

SUPPLEMENTAL AMENDMENT

Box Non-Fee Amendment
Commissioner for Patents
Washington, DC 20231

Dear Sir:

In further response to the Office Action dated September 4, 2002 (Paper No. 4), please amend the above-identified U.S. patent application as follows:

In the Claims

Please amend claims 32-33, 35-37, 39-40 and 42-44 as follows:

32. (Amended) The memory, as set forth in claim 31, wherein the first line is

embedded in the substrate.

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